Ethernet / SATA LVCMOS Clock Generator

Features

- Single LVCMOS output
- Supports 70MHz - 170MHz output frequency range
- RMS phase jitter @ 155.52MHz, (1.875MHz – 20MHz): 0.2ps (typical)
- Full 3.3V or 2.5V supply modes
- Industrial ambient operating temperature
- Available in lead-free package: 8-TSSOP

Description

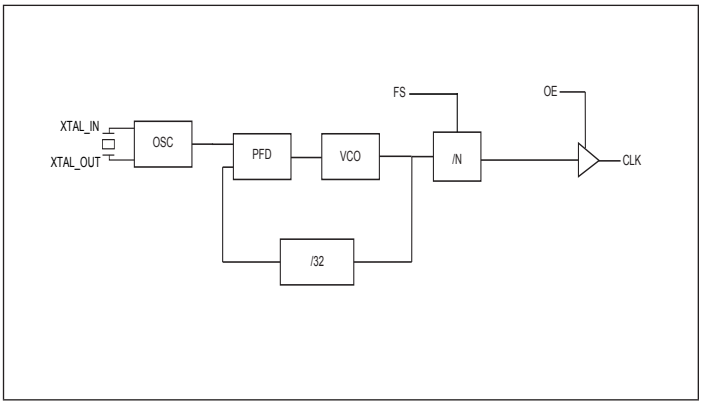
The PI6LC48C51 is a single LVCMOS output synthesizer optimized to generate Ethernet, SONET/SDH, or SATA reference clock frequencies and is a member of Pericom's HiFlex family of high performance clock solutions. Using a MHz crystal with different frequencies, It can generate various output frequencies with very low phase jitter.

It is ideal for Ethernet, SONET/SDH, and SATA/SAS interfaces in all kind of systems.

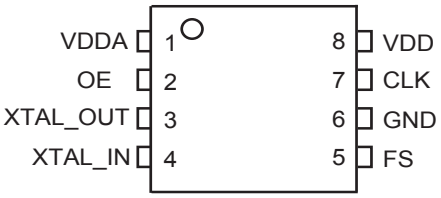
Applications

- Networking systems
- SONET / SDH systems
- Server / Storage Systems

Block Diagram



Pin Configuration



Pinout Table

Pin No.	Pin Name	I/O Type		Description
1	VDDA	Power		Analog Power Supply
2	OE	Input	Pull-up	High: Output enabled; Low: Output high impedence
3, 4	XTAL_OUT, XTAL_IN	Crystal		Crystal Input and Output
5	FS	Input	Pull-down	Output Frequency Select
6	GND	Power		Ground
7	CLK	Output		Output Clock
8	VDD	Power		Power Supply

Output Frequency Table

FS	Crystal Frequency (MHz)	Output Frequency (MHz)
0	20.141601	161.132812
1		80.566406
0	19.53125	156.25
1		78.125
0	19.44	155.52
1		77.76
0	18.75	150
1		75

Typical Crystal Requirement

Parameter	Minimum	Typical	Maximum	Units
Mode of Oscillation		Fundamental		
Frequency	17.5		21.25	MHz
Equivalent Series Resistance (ESR)			50	Ω
Shunt Capacitance			7	pF
Drive Level			1	mW

Recomended Crystal Specification

Pericom recommends:
a) FLxxxx, SMD 3.2x2.5(4P), xxxMHz, CL=18pF, +/-20ppm
http://www.pericom.com/pdf/datasheets/se/FL.pdf

b) b) FYxxxxx, SMD 5x3.2(4P), xxxMHz, CL=18pF, +/-30ppm
http://www.pericom.com/pdf/datasheets/se/FY_F9.pdf

Maximum Ratings (Over operating free-air temperature range)

Storage Temperature..... -65°C to+155°C
Ambient Temperature with Power Applied.....-40°C to+85°C
3.3V Analog Supply Voltage.....-0.5 to +3.6V
ESD Protection (HBM) 2000V

Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

DC Electrical Characteristics

Power Supply DC Characterisitcs, ($V_{DD} = V_{DDA}$, T_A = -40 to 85°C)

Symbol	Parameter	Condition	Min	Typ	Max	Units
V_{DD}, V_{DDA}	Core, Analog Supply Voltage		3.135	3.3	3.465	V
V_{DD}, V_{DDA}	Core, Analog Supply Voltage		2.375	2.5	2.625	V
I_{DD}	Power Supply Current				45	mA
I_{DDA}	Analog Supply Current				30	mA

DC Electrical Characteristics, ($V_{DD} = V_{DDA}$, T_A = -40 to 85°C)

Symbol	Parameter		Condition	Min	Typ	Max	Units
V_{IH}	Input High Voltage		V_{DD} = 3.3V ±5%	2		V_{DD} +0.3	V
			V_{DD} = 2.5V ±5%	1.7		V_{DD} +0.3	
V_{IL}	Input Low Voltage		V_{DD} = 3.3V ±5%	-0.3		0.8	V
			V_{DD} = 2.5V ±5%	-0.3		0.7	
V_{OH}	Output High Voltage		V_{DD} = 3.3V±5%, I_{OH} = - 8mA	2.6			V
			V_{DD} = 2.5V±5%, I_{OH} = - 4mA	90% VDD			
V_{OL}	Output Low Voltage		V_{DD} = 3.3V±5%, I_{OL} = 8mA			0.4	V
			V_{DD} = 3.3V±5%, I_{OL} = 4mA			10% VDD	
I_{IH}	Input High Current	OE, FS	V_{DD} = V_{IN} = 3.465V			5, 150	uA
I_{IL}	Input Low Current	OE, FS	V_{DD} = 3.465V, V_{IN} = 0V	-150,-5			uA

Pin Characteristics

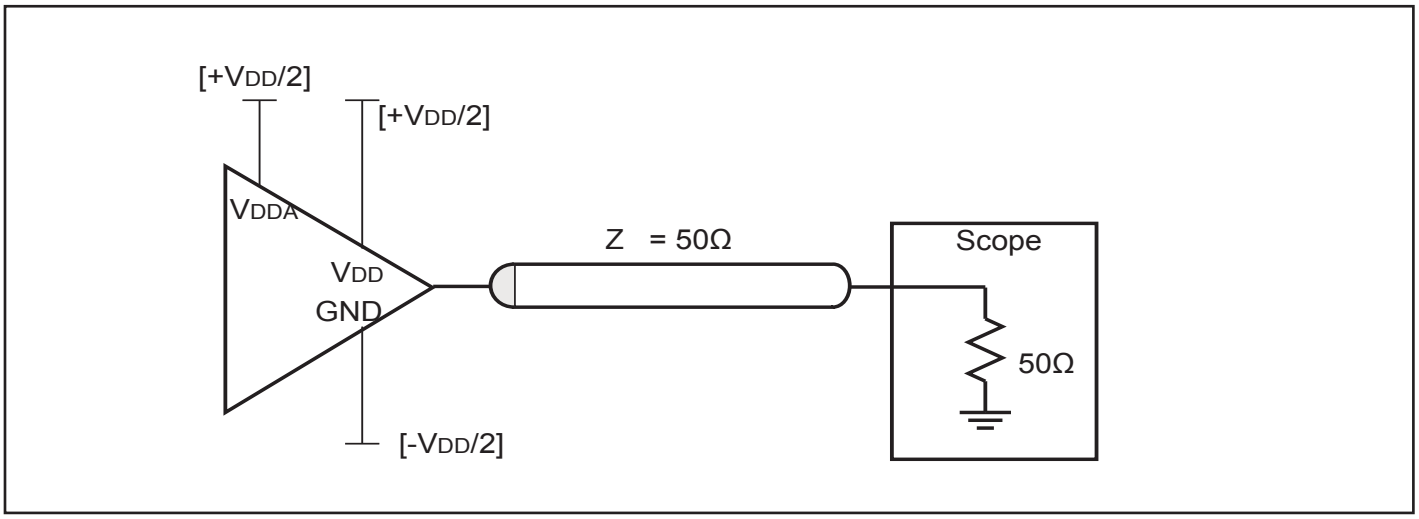
Symbol	Parameter	Min	Typ	Max	Units
C_{JN}	Input Capacitance		4		pF
R_{PULLUP}	Pull up resistor		51		kΩ
$R_{PULLDOWN}$	Pull down resistor		51		kΩ
R_{OUT}	Output Impedence		15		Ω

AC Electrical Characteristics, ($V_{DD} = V_{DDA}$, T_A = -40 to 85°C)

Symbol	Parameter	Condition	Min.	Typ.	Max	Units
f_{OUT}	Output Frequency		70		170	MHz
$t_{jit(Ø)}$	RMS Phase Jitter, (Random)(1)	155.52MHz, (1.875MHz - 20MHz)		0.2		ps
		77.76MHz, (1.875MHz - 20MHz)		0.25		ps
t_R / t_F	Output Rise/Fall Time	20% to 80%	200		800	ps
o_{DC}	Output Duty Cycle		48		52	%

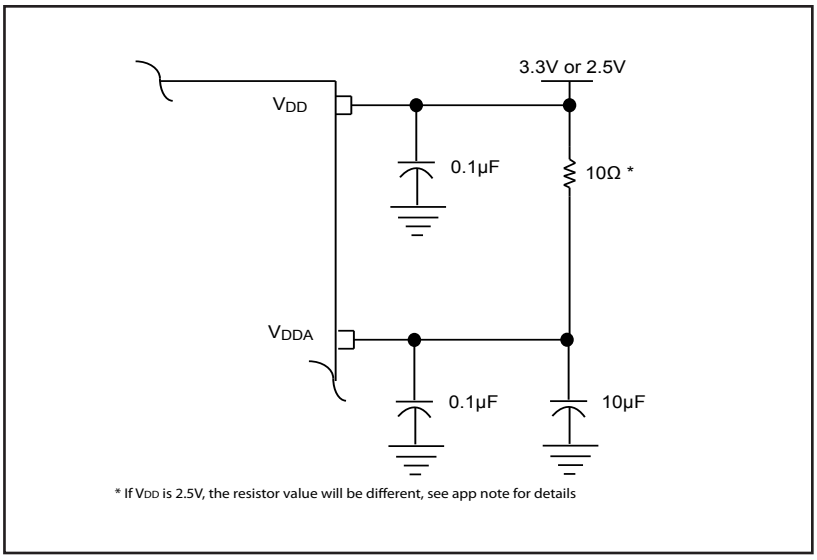
Note:
1. Please refer to the Phase Noise Plots.

LVCMOS Test Circuit



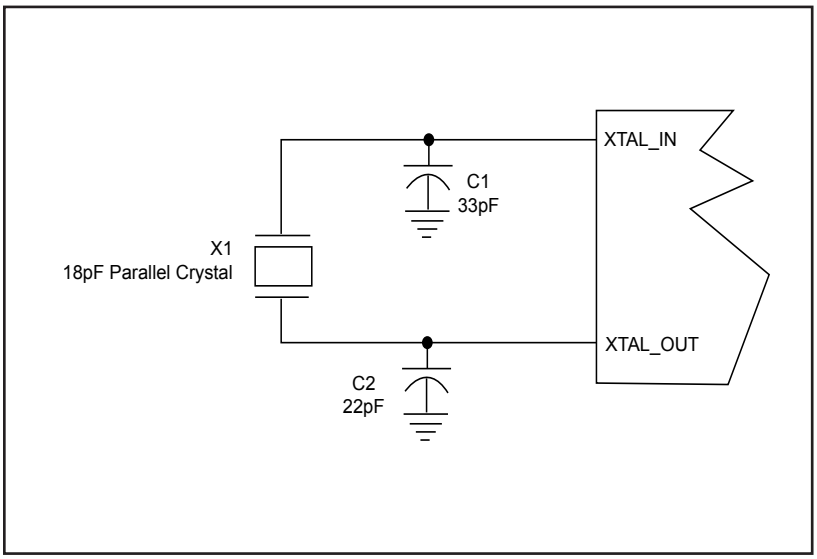
Power Supply Filtering Techniques

As in any high speed analog circuitry, the power supply pins are vulnerable to random noise. To achieve optimum jitter performance, power supply isolation is required. The PI6LC48C51 provides separate power supplies to isolate any high switching noise from the outputs to the internal PLL. V_{DD} and V_{DDA} should be individually connected to the power supply plane through vias, and 0.1µF bypass capacitors should be used for each pin. Figure below illustrates this for a generic V_{DD} pin and also shows that V_{DDA} requires that an additional 10Ω resistor along with a 10µF bypass capacitor be connected to the V_{DDA} pin.



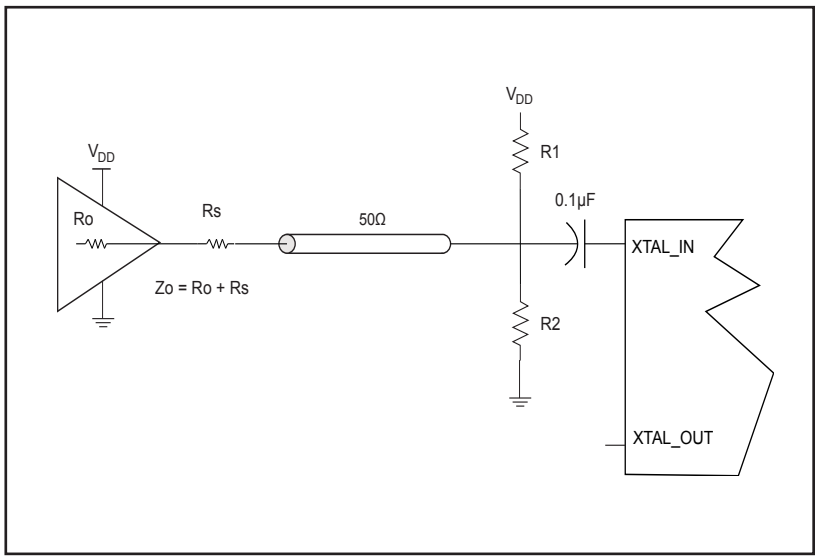
Crystal Input Interface

The clock generator has been characterized with 18pF parallel resonant crystals. The capacitor values shown in the figure below were determined using a 17.5~21.25MHz, 18pF parallel resonant crystal and were chosen to minimize the ppm error.

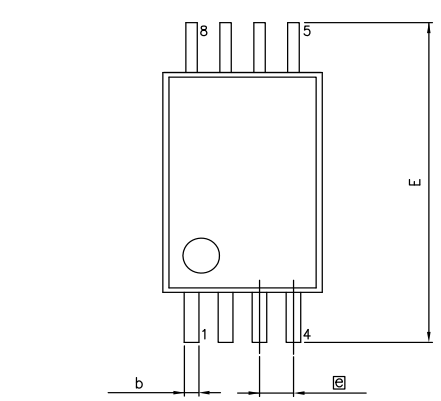


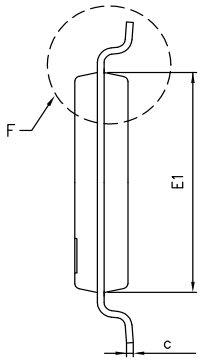
LVCMOS to XTAL Interface

The XTAL_IN input can accept a single-ended LVCMOS signal through an AC coupling capacitor. A general interface diagram is shown in the figure below. The XTAL_OUT pin can be left floating. The input edge rate can be as slow as 10ns. For LVCMOS signals, it is recommended that the amplitude be reduced from full swing to half swing in order to prevent signal interference with the power rail and to reduce noise. This configuration requires that the output impedance of the driver (Ro) plus the series resistance (Rs) equals the transmission line impedance. In addition, matched termination at the crystal input will attenuate the signal in half. This can be done in one of the two ways. First, R1 and R2 in parallel should equal the transmission line empedance. For most 50Ω applications, R1 and R2 can be 100Ω. This can also be accomplished by removing R1 and making R2 50Ω. By overdriving the crystal oscillator, the device will be functional, but note, the device performance is quaranteed by using a quartz crystal.



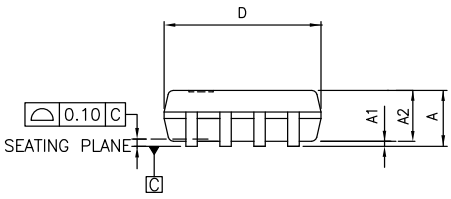
Packaging Mechanical: 8-Contact TSSOP (L)

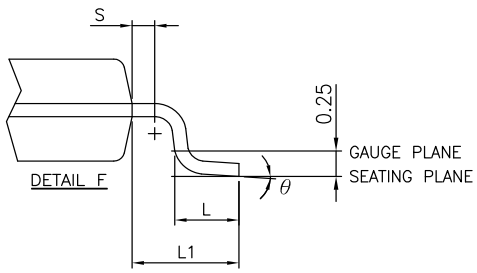




SYMBOLS	MIN.	NOM.	MAX.
A	–	–	1.20
A1	0.05	–	0.15
A2	0.80	–	1.05
b	0.19	–	0.30
c	0.09	–	0.20
D	2.90	3.00	3.10
E		6.40 BSC	
e		0.65 BSC	
E1	4.30	4.40	4.50
L	0.45	0.60	0.75
L1		1.00 REF	
S	0.20	–	–
θ°	0	–	8

UNIT : MM





Notes:
1. Refer JEDEC MO-153F/AA
2. Controlling dimensions in millimeters
3. Package outline exclusive of mold flash and metal burr

PERICOM Enabling Serial Connectivity — **DATE: 05/03/12**

DESCRIPTION: 8 pin, 173mil wide TSSOP

PACKAGE CODE: L

DOCUMENT CONTROL #: PD-1308 **REVISION: F**

12-0370

Ordering Information

Ordering Code	Packaging Type	Package Description	Operating Temperature
PI6LC48C51LIE	L	Pb-free & Green, 8-pin TSSOP	Industrial
PI6LC48C51LIEX	L	Pb-free & Green, 8-pin TSSOP, Tape & Reel	Industrial

Notes:

- Thermal characteristics can be found on the company web site at www.pericom.com/packaging/
- "E" denotes Pb-free and Green
- Adding an "X" at the end of the ordering code denotes tape and reel packaging

单击下面可查看定价，库存，交付和生命周期等信息

>>Diodes Incorporated(达迩科技（美台）)